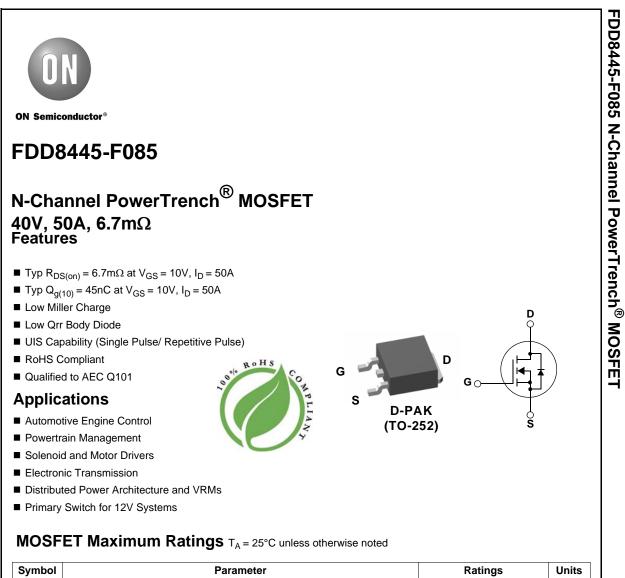
ON Semiconductor

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Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage		40	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (V _{GS} = 10V)		50	^
I _D	Pulsed		Figure 4	Α
E _{AS}	Single Pulse Avalanche Energy	(Note 1)	144	mJ
_	Power Dissipation		79	W
P _D	Derate above 25°C		0.53	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to +175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		1.9	°C/W
R _{0JA}	Thermal Resistance Junction to Ambient, 1in ² copper pad a	area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8445	FDD8445-F085	TO-252AA	13"	12mm	2500 units

Notes:

1: Starting $T_J = 25^{\circ}$ C, L = 0.18mH, $I_{AS} = 40A$ 2: A suffix as "...F085P" has been temporarily introduced in order to manage a double source strategy as ON Semiconductor has officially announced in Aug 2014.

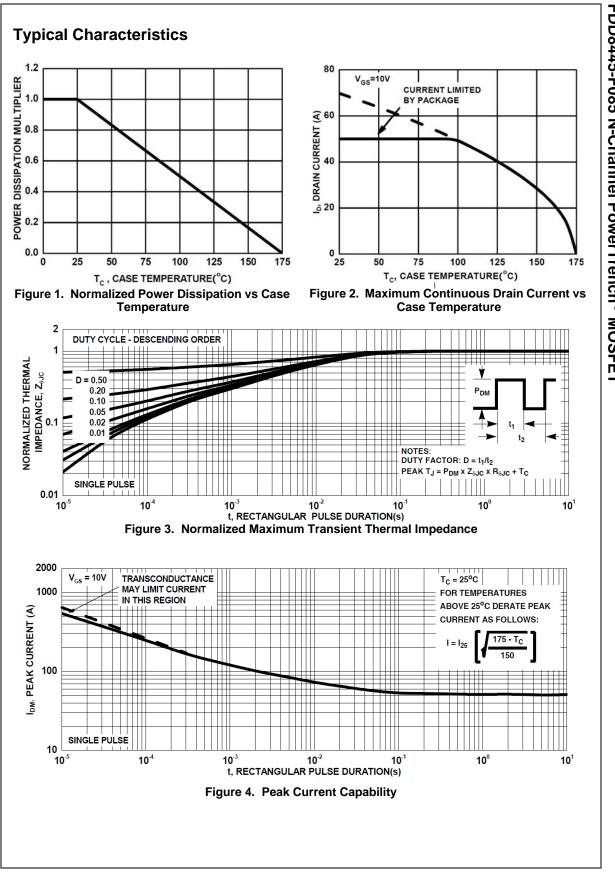
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Cha	racteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	40	-	-	V	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 32V$,	-	-	1	μA	
		$V_{GS} = 0V \qquad T_A = 150^{\circ}C$	-	-	250 ±100	nA	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA	
	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2	2.8	4		
		I _D = 50A, V _{GS} = 10V	-	6.7	8.7	mΩ	
r _{DS(on)}	Drain to Source On Resistance	I _D = 50A, V _{GS} = 10V T _J = 175 ^o C	-	12.5	16.3		
Dynami	ic Characteristics						
				3040	4050		
C _{iss}	Input Capacitance		-	3040	4030	pF	
C _{iss} C _{oss}	Input Capacitance Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$	-	295	390	p⊢ pF	
		$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz	-				
C _{oss} C _{rss}	Output Capacitance		- - -	295	390	pF	
C _{oss} C _{rss} R _G	Output Capacitance Reverse Transfer Capacitance	f = 1MHz		295 178	390	pF pF	
C _{oss} C _{rss} R _G Q _{g(TOT)}	Output Capacitance Reverse Transfer Capacitance Gate Resistance	f = 1MHz f = 1MHz		295 178 1.7	390 270 -	pF pF Ω	
C _{oss} C _{rss} R _G	Output Capacitance Reverse Transfer Capacitance Gate Resistance Total Gate Charge at 10V	$f = 1 MHz$ $f = 1 MHz$ $V_{GS} = 0 \text{ to } 10V$		295 178 1.7 45	390 270 - 59	pF pF Ω nC	

Switching Characteristics

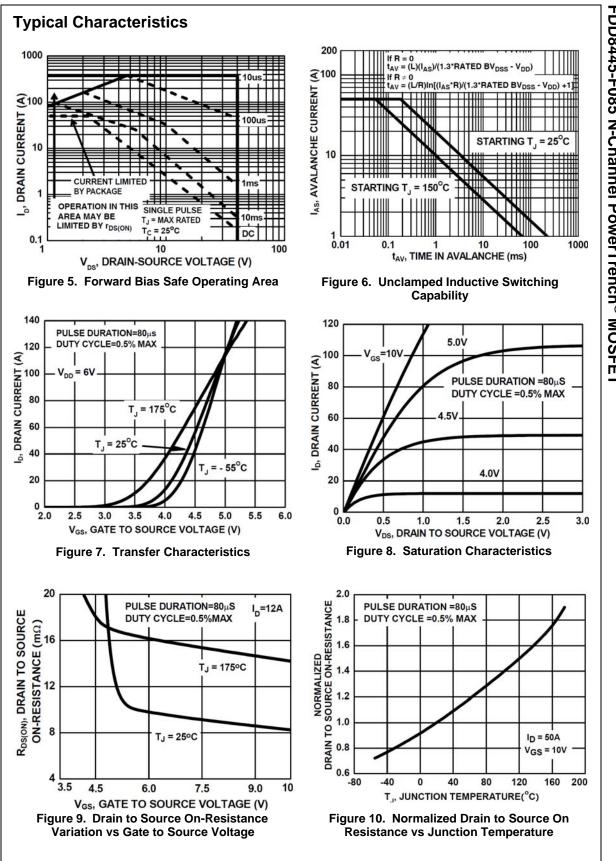
t _{on}	Turn-On Time		-	-	138	ns
t _{d(on)}	Turn-On Delay Time		-	10	-	ns
t _r	Rise Time	$V_{DD} = 20V, I_D = 50A$ $V_{GS} = 10V, R_{GS} = 2\Omega$	-	82	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 100, R_{GS} = 202$	-	26	-	ns
t _f	Fall Time		-	9.6	-	ns
t _{off}	Turn-Off Time		-	-	53	ns

Drain-Source Diode Characteristics

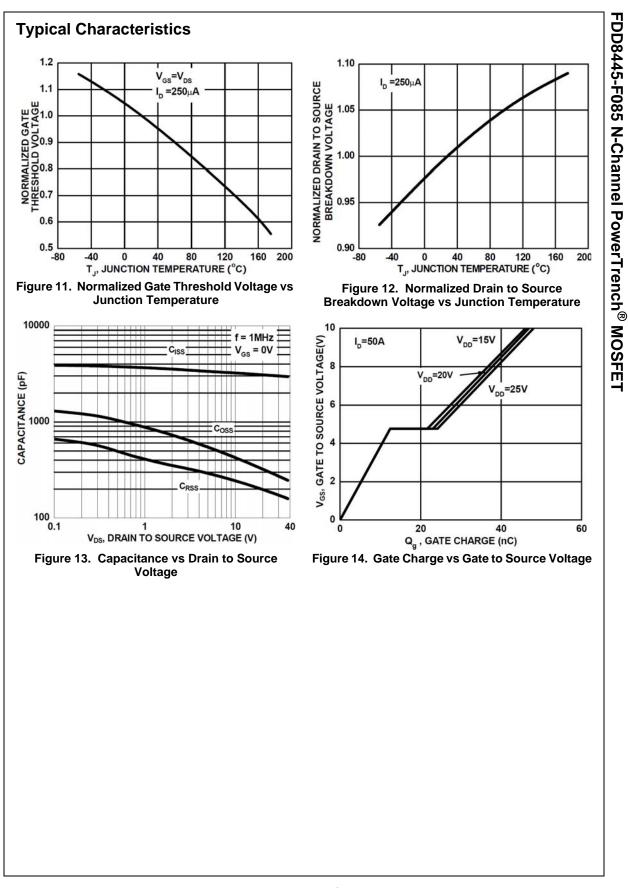
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 50A	-	-	1.25	V
		I _{SD} = 25A	-	-	1.0	v
t _{rr}	Reverse Recovery Time	$I_{SD} = 50A$, $dI_{SD}/dt = 100A/\mu s$	-	-	39	ns
Q _{rr}	Reverse Recovery Charge		-	-	38	nC



FDD8445-F085 N-Channel PowerTrench[®] MOSFET



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